X8R/X8L Dielectric

General Specifications



AVX has developed a range of multilayer ceramic capacitors designed for use in applications up to 150°C. These capacitors are manufactured with an X8R and an X8L dielectric material. X8R material has capacitance variation of ± 15% between -55°C and +150°C. The X8L material has capacitance variation of ±15% between -55°C to 125°C to 125°C and +15/40% from +125°C to +150°C.



The need for X8R and X8L performance has been driven by customer requirements for parts that operate at elevated temperatures. They provide a highly reliable capacitor with low loss and stable capacitance over temperature.

They are ideal for automotive under the hood sensors, and various industrial applications. Typical industrial application would be drilling monitoring system. They can also be used as bulk capacitors for high temperature camera modules.

Both X8R and X8L dielectric capacitors are automotive AEC-Q200 qualified. Optional termination systems, tin, FLEXITERM[®] and conductive epoxy for hybrid applications are available. Providing this series with our FLEXITERM[®] termination system provides further advantage to customers by way of enhanced resistance to both, temperature cycling and mechanical damage.

0805	5	Α	104	K	4	Т	2	A
Size	Voltage	Dielectric	Capacitance	Capacitance	Failure	Terminations	Packaging	Special Code
0402 0603 0805 1206	10V = Z 16V = Y 25V = 3 50V = 5 100V = 1	X8R = F X8L = L	Code (in pF) 2 Sig. Digits + Number of Zeros e.g. 10 F = 106	Tolerance J = ±5% K = ±10% M = ±20%	Rate 4=Automotive A = Not Applicable	T = Plated Ni and Sn Z = FLEXITERM ^{®∗∗}	2 = 7" Reel 4 = 13" Reel	A = Std. Product

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

				X8F	2										Χ	8L							
S	Size		06	03	0	805	1	206		Size		0603			0805			12	06			1210	
Soldering			Reflow	/Wave	Reflo	w/Wave	Reflow/Wave			Soldering R		eflow/Wave		Re	Reflow/Wave			Reflow	//Wave		Re	Reflow/Wave	
	Ŵ		25V	50V	25V	50V	25V	50V		WVDC	25V	50V	100V	25V	50V	100V	16V	25V	50V	100V	10V	50V	100V
		270	G	G					271			G											
	oF)	330	G	G	J	J			331			G	G	J	J	J							
471		470	G	G	J	J			471			G	G	J	J	J							
681		680	G	G	J	J			681 102			G G	G G	J J	J	J J			J				
102		000 500	G G	G G	J	J	J	J	152			G	G	J	J	J		J	J	J			
222		200	G	G	J	J	J	J	182			G	G	J	J	J		J	J	J			
332		300	G	G	J	J	J	J	222			G	G	J	J	J		J	J	J			
472		700	G	G	J	J	J	J	272			G	G	J	J	J		J	J	J			
682		800	G	G	J	J	J	J	332			G	G	J	J	J		J	J	J			
		0.01	G	G	J	J	J	J	392	3900	G	G	G	J	J	J		J	J	J			
153 (µ	ιF) 0.	015	G	G	J	J	J	J	472			G	G	J	J	J		J	J	J			
223		022	G	G	J	J	J	J	562			G	G	J	J	J		J	J	J			
333		033	G	G	J	J	J	J	682			G	G	J	J	J		J	J	J			
473		047	G	G	J	J	J	J	822			G	G	J	J	J		J	J	J	L		
683	0.	068	G		N	N	M	M	103			G	G	J	J	J		J	J	J			
104		0.1			N	N	M	M	123			G		J	J	J		J	J	J			
154).15			N	N	M	M	153			G G		J J	J	J		J	J	J			
224).22			N		M	M	223			G		J	J	J		J	J	J			
334 474		0.33				-	M	M	273			G		J	J	J		J	J	J			
684).68					IVI		333			G		J	J	N		J	J	J			
105		1							393			G		J	J	N		J	J	J			
155		1.5						1	473			G		J	J	N		J	J	J			
225		2.2						1	563			G		J	J	N		J	J	J			
	W	/DC	25V	50V	25V	50V	25V	50V	683			G		J	J	N		J	J	J			
S	IZE		06		0	805		206	823	0.082	G	G		J	J	N		J	J	J			
									104			G		J	J	N		J	J	М			
Size			03	080	5	1206		1210	124					J	N			J	J	М			
Solder	ring	Reflow	v/Wave	Reflow/V	Vave	Reflow/Wav	e Re	low/Wave	154					J	N		J	J	J	Q			
Packag	ging	All P	Paper	Paper//Emb	bossed P	aper/Emboss	ed Pape	r/Embosse	d 184					Ν	N		J	J	J	Q			
	mm	1.60 =	± 0.15	2.01 ± 0).20	3.20 ± 0.20	3.	30 ± 0.4	224					N	N		J	J	J	Q			
(L) Length	(in)	(0.063 =	± 0.006)	(0.079 ± 0).008) ((0.126 ± 0.00	8) (0.1	30 ± 0.016	274					N			J	M	M	Q			
	mm		± 0.15	1.25 ± 0		1.60 ± 0.20		60 ± 0.20	334					N	-		J	M	M	Q			
(W) Width	(in)		± 0.006)	(0.049 ± 0		(0.063 ± 0.00)	_	8 ± 0.008	394					N N			M	M	P P	Q			
	mm		± 0.000)	0.50 ± 0		0.50 ± 0.25		6 ± 0.000) 474 684					N			M	M	P	Q Q			
(t) Terminal	(in)		± 0.15 ± 0.006)	(0.020 ± 0		0.30 ± 0.23 (0.020 ± 0.01		$\frac{100 \pm 0.23}{20 \pm 0.010}$						N			M	M	P	Q			
	(11)	1(0.014 5	± 0.000)	(0.020 ± 0	.010) [((0.020 ± 0.01)	0) [(0.0.	.0 ± 0.010	105					N	-		M	M	P	Q			
									155								M	M		~			
									225								M	M				Z	Z
									475	;												Ζ	
									106	;											Ζ		
										WVDC	25V	50V	100V	25V	50V	100V	16V	25V	50V	100V	10V	50V	100V
										SIZE		0603			0805			12	06			1210	
				1						1 1										= AEC-	0200		
	L	etter	A	С		E	G	J	К	M	Ν	P		Q	Х	Y		Z		= AEC-0 Quali			
	N	lax.	0.33	0.56	3 0	.71 0	.9	0.94	1.02	1.27	1.4	1.52	2 1	.78	2.29	2.5	54	2.79					
		kness	(-0.013	3) (-0.02	2) (-0	.028) (-0.	035) (-0.037)	(-0.04)	(-0.05) (-0.055)	(-0.0	6) (-().07)	(-0.09)	(-0.	1) (-0.11)	1				
		-	(0.010	, (0.02	, ,	APER			(0.04)	(0.00) (2.000)		BOSSE		(0.00)	(0.	., [()					
					PA								5033E	.U					J				
										/.\V/	\ \ /	B											



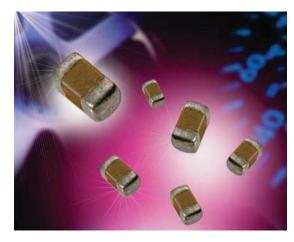
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X8R/X8L Dielectric

General Specifications

APPLICATIONS FOR X8R AND X8L CAPACITORS

- All market sectors with a 150°C requirement
- Automotive on engine applications
- · Oil exploration applications
- · Hybrid automotive applications
 - Battery control
 - Inverter / converter circuits
 - Motor control applications
 - Water pump
- · Hybrid commercial applications
 - Emergency circuits
 - Sensors
 - Temperature regulation



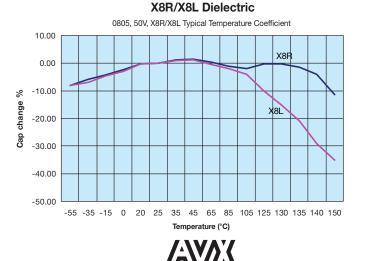


ADVANTAGES OF X8R AND X8L MLC CAPACITORS

- Both ranges are qualified to the highest automotive AEC-Q200 standards
- Excellent reliability compared to other capacitor technologies
- · RoHS compliant
- · Low ESR / ESL compared to other technologies
- · Tin solder finish
- FLEXITERM® available
- · Epoxy termination for hybrid available
- 100V range available

ENGINEERING TOOLS FOR HIGH VOLTAGE MLC CAPACITORS

- · Samples
- Technical Articles
- Application Engineering
- Application Support



X8R/X8L Dielectric

Specifications and Test Methods

Parame	ter/Test	X8R/X8L Specification Limits	Measuring Conditions					
Operating Tem		-55°C to +150°C	Temperature Cycle Chamber					
Сарас	itance	Within specified tolerance	Freq.: 1.0 kHz ± 10%					
Dissipatio	on Factor	\leq 2.5% for \geq 50V DC rating	Voltage: 1	.0Vrms ± .2V				
Diocipatio		≤ 3.5% for 25V DC and 16V DC rating						
Insulation	Resistance	100,000MΩ or 1000MΩ - μF,	Charge device with rated voltage for					
moulation		whichever is less	120 ± 5 secs @	room temp/humidity				
Dielectric	Strength	No breakdown or visual defects	1-5 seconds, w/charg limited to Note: Charge devic	50% of rated voltage for e and discharge current 50 mA (max) ce with 150% of rated 500V devices.				
	Appearance	No defects	Deflect	tion: 2mm				
	Capacitance		Test Time: 30 seconds					
Resistance to	Variation	≤ ±12%	7	1mm/sec				
Flexure	Dissipation		_	V				
Stresses	Factor	Meets Initial Values (As Above)						
	Insulation	≥ Initial Value x 0.3	90 mm					
	Resistance							
Solder	rability	≥ 95% of each terminal should be covered	Dip device in eutectic solder at 230 ± 5°C					
Solder	-	with fresh solder	for 5.0 ±	0.5 seconds				
	Appearance	No defects, <25% leaching of either end terminal	_					
	Capacitance	≤ ±7.5%	 Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± 2 hours before measuring electrical properties. 					
	Variation							
Resistance to	Dissipation	Meets Initial Values (As Above)						
Solder Heat	Factor							
Conden mout	Insulation	Meets Initial Values (As Above)		0 1 1				
	Resistance		_					
	Dielectric	Meets Initial Values (As Above)						
	Strength Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes				
	Capacitance		· · · ·					
	Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes				
	Dissipation							
Thermal	Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes				
Shock	Insulation							
	Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes				
	Dielectric	Mooto Initial Values (As Above)	Repeat for 5 cycles and measure after					
	Strength	Meets Initial Values (As Above)	24 ± 2 hours at room temperature					
	Appearance	No visual defects	Charge device with 1.5 rated voltage (≤ 10V) in					
	Capacitance	≤ ±12.5%						
	Variation			et at 150°C ± 2°C				
	Dissipation	≤ Initial Value x 2.0 (See Above)	for 1000 hours (+48, -0)					
Load Life	Factor			ala anala an an al atal 12				
	Insulation	\geq Initial Value x 0.3 (See Above)		chamber and stabilize				
	Resistance		at room temperature for 24 ± 2 hours before measuring.					
	Dielectric	Meets Initial Values (As Above)						
	Strength	No visual defects						
	Appearance Capacitance		Store in a test cham	ber set at 85°C ± 2°C/				
	Variation	≤ ±12.5%	85% ± 5% relative humidity for 1000 hours (+48, -0) with rated voltage applied.					
Load	Dissipation							
Humidity	Factor	\leq Initial Value x 2.0 (See Above)						
numialty	Insulation		 Remove from chamber and stabilize at 					
		≥ Initial Value x 0.3 (See Above)	room temperature and humidity for					
	Resistance	· · · · · · · · · · · · · · · · · · ·		24 ± 2 hours before measuring.				
	Resistance Dielectric	Meets Initial Values (As Above)	24 ± 2 hours b	efore measuring.				

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